

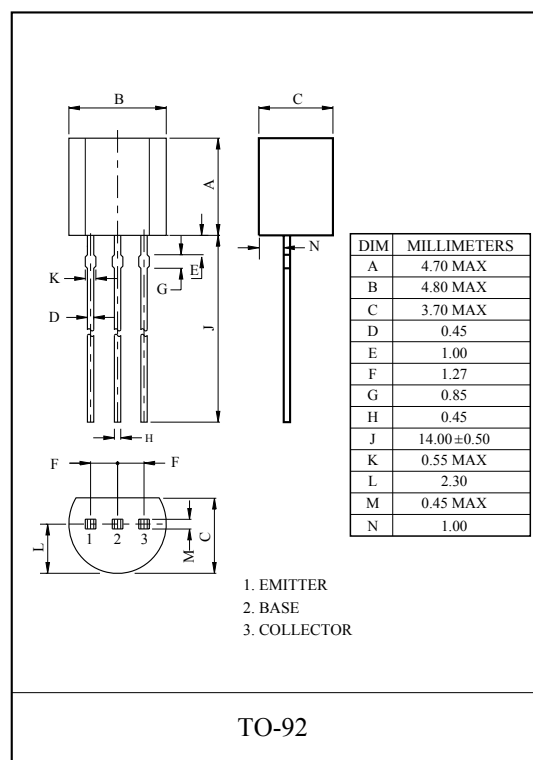
GENERAL PURPOSE APPLICATION.  
SWITCHING APPLICATION.

## FEATURES

- Low Leakage Current  
:  $I_{CEX}=50nA(\text{Max.})$ , @ $V_{CE}=30V$ ,  $V_{EB}=3V$ .
- Low Saturation Voltage  
:  $V_{CE(sat)}=0.3V(\text{Max.})$  @ $I_C=50mA$ ,  $I_B=5mA$ .
- Complementary to KN3906.

## MAXIMUM RATING (Ta=25℃)

CHARACTERISTIC	SYMBOL	RATING	UNIT
Collector-Base Voltage	$V_{CBO}$	60	V
Collector-Emitter Voltage	$V_{CEO}$	40	V
Emitter-Base Voltage	$V_{EBO}$	6	V
Collector Current	$I_C$	200	mA
Base Current	$I_B$	50	mA
Collector Power Dissipation	$P_C$	625	mW
Junction Temperature	$T_j$	150	℃
Storage Temperature Range	$T_{stg}$	-55 ~ 150	℃



# KN3904

## ELECTRICAL CHARACTERISTICS (Ta=25℃)

CHARACTERISTIC	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNIT
Collector Cut-off Current	$I_{CEX}$	$V_{CE}=30V, V_{EB}=3V$	-	-	50	nA
Collector-Base Breakdown Voltage	$V_{(BR)CBO}$	$I_C=10\mu A, I_E=0$	60	-	-	V
Collector-Emitter Breakdown Voltage *	$V_{(BR)CEO}$	$I_C=1mA, I_B=0$	40	-	-	V
Emitter-Base Breakdown Voltage	$V_{(BR)EBO}$	$I_E=10\mu A, I_C=0$	6	-	-	V
DC Current Gain *	$h_{FE(1)}$	$V_{CE}=1V, I_C=0.1mA$	40	-	-	
	$h_{FE(2)}$	$V_{CE}=1V, I_C=1mA$	70	-	-	
	$h_{FE(3)}$	$V_{CE}=1V, I_C=10mA$	100	-	300	
	$h_{FE(4)}$	$V_{CE}=1V, I_C=50mA$	60	-	-	
	$h_{FE(5)}$	$V_{CE}=1V, I_C=100mA$	30	-	-	
Collector-Emitter Saturation Voltage *	$V_{CE(sat)1}$	$I_C=10mA, I_B=1mA$	-	-	0.2	V
	$V_{CE(sat)2}$	$I_C=50mA, I_B=5mA$	-	-	0.3	
Base-Emitter Saturation Voltage *	$V_{BE(sat)1}$	$I_C=10mA, I_B=1mA$	0.65	-	0.85	V
	$V_{BE(sat)2}$	$I_C=50mA, I_B=5mA$	-	-	0.95	
Transition Frequency	$f_T$	$V_{CE}=20V, I_C=10mA, f=100MHz$	-	300	-	MHz
Collector Output Capacitance	$C_{ob}$	$V_{CB}=5V, I_E=0, f=1MHz$	-	-	4.0	pF

\* Pulse Test : Pulse Width  $\leq 300\mu s$ , Duty Cycle  $\leq 2\%$ .

